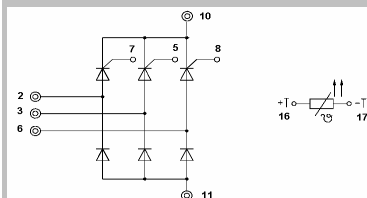



MiniSKiiP 8

Absolute Maximum Ratings			
Symbol	Conditions ¹⁾	Values	Units
Bridge rectifier			
V_{RRM}		1500	V
I_D	$T_{heatsink} = 80\text{ °C}$	125 ³⁾	A
I_{FSM}/I_{TSM}	$t_p = 10\text{ ms}; \sin. 180\text{ °C}, T_j = 25\text{ °C}$	1000	A
I^2t	$t_p = 10\text{ ms}; \sin. 180\text{ °C}, T_j = 25\text{ °C}$	5000	A ² s
T_j	Diode	-40...+150	°C
T_j	Thyristor	-40...+125	°C
T_{stg}		-40...+125	°C
V_{isol}	AC, 1 min.	2500	V

**MiniSKiiP 8
SEMIKRON integrated
intelligent Power**
**SKiiP 83 AH 15 T1
3-phase bridge rectifier**
Preliminary Data


Characteristics					
Symbol	Conditions ¹⁾	min.	typ.	max.	Units
Diode - Rectifier					
V_F	$I_F = 100A \quad T_j = 125\text{ °C}$	-	1,15	-	V
V_{TO}	$T_j = 125\text{ °C}$	-	0,8	-	V
r_T	$T_j = 125\text{ °C}$	-	3,5	-	mΩ
R_{thjh}	per Diode	-	-	0,7	K/W
Thyristor - Rectifier					
V_T	$I_F = 120A \quad T_j = 125\text{ °C}$	-	-	1,8	V
$V_{T(TO)}$	$T_j = 125\text{ °C}$	-	-	1,1	V
r_T	$T_j = 125\text{ °C}$	-	-	5	mΩ
R_{thjh}	per Thyristor	-	-	0,9	K/W
I_{GD}	$T_j = 125\text{ °C}$	5	-	-	mA
V_{GT}	$T_j = 25\text{ °C}$	-	-	3	V
I_{GT}	$T_j = 25\text{ °C}$	-	-	150	mA
I_H	$T_j = 25\text{ °C}$	-	250	-	mA
I_L	$T_j = 25\text{ °C}$	-	600	-	mA
dv/dt_{CR}	$T_j = 125\text{ °C}$	500	-	-	V/μs
di/dt_{CR}	$T_j = 125\text{ °C}$	-	-	125	V/μs
Temperature Sensor					
R_{TS}	$T = 25 / 100\text{ °C}$		1000 / 1670		Ω
Mechanical Data					
M_1	case to heatsink, SI Units	2,5	-	3,5	Nm
Case			M8a		

UL recognized file no. E63532
¹⁾ $T_{heatsink} = 25\text{ °C}$, unless otherwise specified

²⁾ CAL = Controlled Axial Lifetime Technology (soft and fast recovery)

³⁾ Limited to 100 A by terminals

This technical information specifies semiconductor devices, but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.